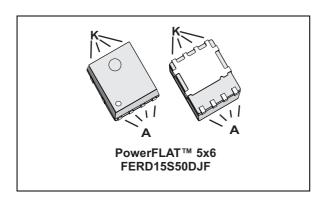


#### Field effect rectifier

Datasheet - production data



**Table 1. Device summary** 

Symbol	Value		
I <sub>F(AV)</sub>	15 A		
V <sub>RRM</sub>	50 V		
T <sub>j</sub> (max)	+150 °C		
V <sub>F</sub> (typ)	0.30 V		

#### **Features**

- ST proprietary process
- Stable leakage current over reverse voltage
- Low forward voltage drop
- High frequency operation

### **Description**

This single rectifier is based on a proprietary technology, enabling to achieve the best in class  $V_{\text{F}}/I_{\text{R}}$  for a given silicon surface.

Packaged in PowerFLAT™ 5x6, this device is intended to be used in rectification and freewheeling operations in switch mode power supplies.

TM: PowerFLAT is a trademark of STMicroelectronics

Characteristics FERD15S50

## 1 Characteristics

Table 2. Absolute ratings (limiting values, per diode, at 25 °C, unless otherwise specified)

Symbol	Parameter			Unit	
$V_{RRM}$	Repetitive peak reverse voltage			V	
I <sub>F(RMS)</sub>	Forward rms current			Α	
I <sub>F(AV)</sub>	Average forward current, $\delta = 0.5$	T <sub>c</sub> = 120 °C	15	Α	
I <sub>FSM</sub>	Surge non repetitive forward current $t_p = 10 \text{ ms sinusoidal}$		80	Α	
T <sub>stg</sub>	Storage temperature range		-65 to + 175	°C	
T <sub>j</sub>	Maximum operating junction temperature <sup>(1)</sup>		150	°C	

<sup>1.</sup>  $\frac{dPtot}{dT_j} < \frac{1}{Rth(j-a)}$  condition to avoid thermal runaway for a diode on its own heatsink

Table 3. Thermal resistance

Symbol	Parameter	Value (max)	Unit
R <sub>th(j-c)</sub>	Junction to case	2.8	°C/W

Table 4. Static electrical characteristics

Symbol	Parameter	Test conditions		Min.	Тур.	Max.	Unit
I <sub>R</sub> <sup>(1)</sup> Reverse leakage cu	Povorco lookago gurrant	T <sub>j</sub> = 25 °C	$V_R = V_{RRM}$		250	650	μΑ
IR`′	I <sub>R</sub> <sup>(1)</sup> Reverse leakage current	T <sub>j</sub> = 125 °C			20	40	mA
V <sub>F</sub> <sup>(2)</sup> Forward voltage drop	T <sub>j</sub> = 25 °C	I		0.35			
		T <sub>j</sub> = 125 °C	I <sub>F</sub> = 5 A		0.30	0.35	
	Forward voltage drop	T <sub>j</sub> = 25 °C	1 40 4		0.42	0.48	V
		T <sub>j</sub> = 125 °C	I <sub>F</sub> = 10 A		0.41	0.45	
		T <sub>j</sub> = 25 °C	I <sub>F</sub> = 15 A		0.48		

<sup>1.</sup> Pulse test:  $t_p = 5 \text{ ms}$ ,  $\delta < 2\%$ 

To evaluate the conduction losses use the following equation:

$$P = 0.25 \text{ x } I_{F(AV)} + 0.02 I_{F(RMS)}^{2}$$

<sup>2.</sup> Pulse test:  $t_p$  = 380  $\mu$ s,  $\delta$  < 2%

FERD15S50 Characteristics

Figure 1. Average forward power dissipation versus average forward current

PF(AV)(W) 12  $\delta = 0.5$  $\delta = 0.1$ 10  $\delta = 0.05$ 8 6 0 2 6 8 10 12 14 20 0 16 18

Figure 2. Average forward current versus ambient temperature ( $\delta = 0.5$ )

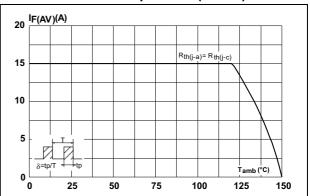
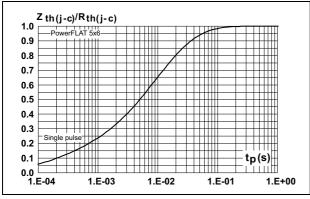


Figure 3. Relative variation of thermal impedance junction to case versus pulse duration

Figure 4. Reverse leakage current versus reverse voltage applied (typical values)



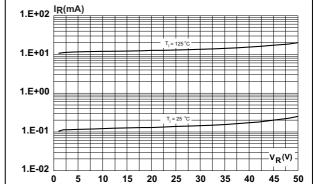
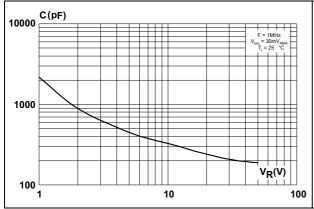
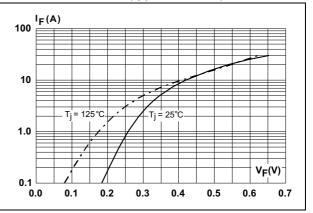


Figure 5. Junction capacitance versus reverse voltage applied (typical values)

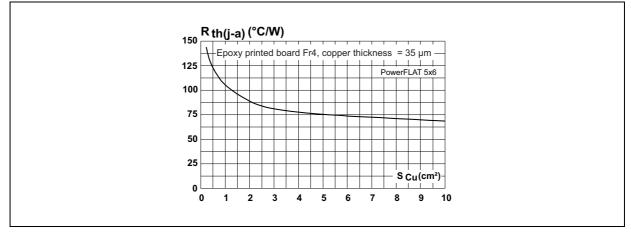
Figure 6. Forward voltage drop versus forward current (typical values)





Characteristics FERD15S50

Figure 7. Thermal resistance junction to ambient versus copper surface under tab (typical values)



## 2 Package information

- Epoxy meets UL94, V0
- Cooling method: by conduction (C)

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK<sup>®</sup> packages, depending on their level of environmental compliance. ECOPACK<sup>®</sup> specifications, grade definitions and product status are available at: <a href="https://www.st.com">www.st.com</a>. ECOPACK<sup>®</sup> is an ST trademark.

 $\begin{array}{c} D2 \\ E2 \\ \hline \\ A1 \\ \hline \\ D \\ \hline \\ A2 \\ \hline \\ E \\ \hline \end{array}$ 

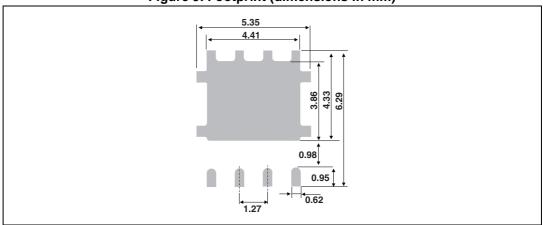
Figure 8. PowerFLAT-8L dimensions (definitions)

Package information FERD15S50

Table 5. PowerFLAT-8L dimensions (values)

	Dimensions						
Ref.	Millimeters			Inches			
	Min.	Тур.	Max.	Min.	Тур.	Max.	
Α	0.80		1.00	0.031		0.039	
A1	0.02		0.05	0.001		0.002	
A2		0.25			0.010		
b	0.30		0.50	0.012		0.020	
D		5.20			0.205		
D2	4.11		4.31	0.162		0.170	
е		1.27			0.050		
Е		6.15			0.242		
E2	3.50		3.70	0.138		0.146	
L	0.50		0.80	0.020		0.031	
K	1.275		1.575	0.050		0.062	

Figure 9. Footprint (dimensions in mm)



# 3 Ordering information

**Table 6. Ordering information** 

Order code	Marking	Package	Weight	Base qty	Delivery mode
FERD15S50DJF-TR	FD15 S50	PowerFLAT™ 5x6	0.095 g	3000	Tape and reel

## 4 Revision history

Table 7. Document revision history

Date	Revision	Changes
09-Oct-2013	1	Initial release.

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